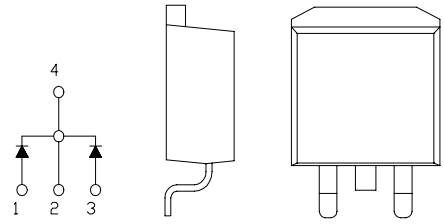


# FRD Type : C16T20F

## OUTLINE DRAWING

### FEATURES

- \* **SQUARE-PAK** TO263AB Case (SMD)  
Packaged in 24mm Tape and Reel
- \* Dual Diodes – Cathode Common
- \* Ultra – Fast Recovery
- \* Low Forward Voltage Drop
- \* High Surge Capability
- \* 200 Volts thru 600 Volts Types Available



### Maximum Ratings

Approx Net Weight:1.4g

Rating	Symbol	C16T20F		Unit
Repetitive Peak Reverse Voltage	$V_{RRM}$	200		V
Non-repetitive Peak Reverse Voltage	$V_{RSM}$	220		V
Average Rectified Output Current	$I_O$	16	$T_c=113^\circ\text{C}$ 50 Hz, Full Sine Wave Resistive Load	A
RMS Forward Current	$I_{F(RMS)}$	18		A
Surge Forward Current	$I_{FSM}$	120	50 Hz Full Sine Wave, 1 cycle Non-repetitive	A
Operating Junction Temperature Range	$T_{jw}$	- 40 to + 150		$^\circ\text{C}$
Storage Temperature Range	$T_{stg}$	- 40 to + 150		$^\circ\text{C}$

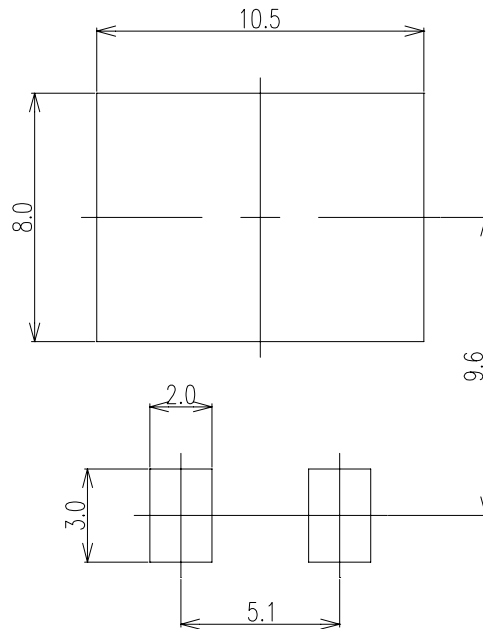
### Electrical • Thermal Characteristics

Characteristics	Symbol	Conditions	Min.	Typ.	Max.	Unit
Peak Reverse Current	$I_{RM}$	$T_j=25^\circ\text{C}, V_{RM}=V_{RRM}$ per Arm	-	-	25	$\mu\text{A}$
Peak Forward Voltage	$V_{FM}$	$T_j=25^\circ\text{C}, I_{FM}=8\text{A}$ per Arm	-	-	0.98	V
Reverse Recovery Time	$t_{rr}$	$I_{FM}= 8 \text{ A},$ $-di/dt= 50 \text{ A}/\mu\text{s}, T_a= 25^\circ\text{C}$	-	-	35	ns
Thermal Resistance	$R_{th(j-c)}$	Junction to Case	-	-	2	$^\circ\text{C}/\text{W}$

C\_T\_ OUTLINE DRAWING (Dimensions in mm)



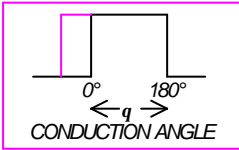
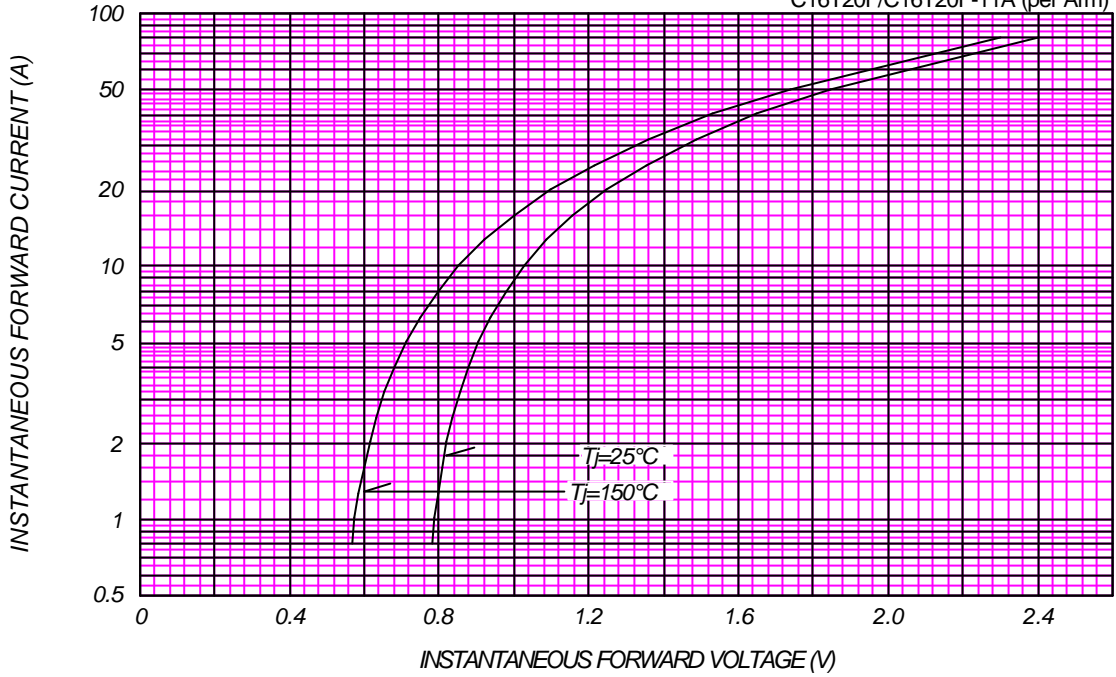
SOLDERING PAD



FORWARD CURRENT VS. VOLTAGE

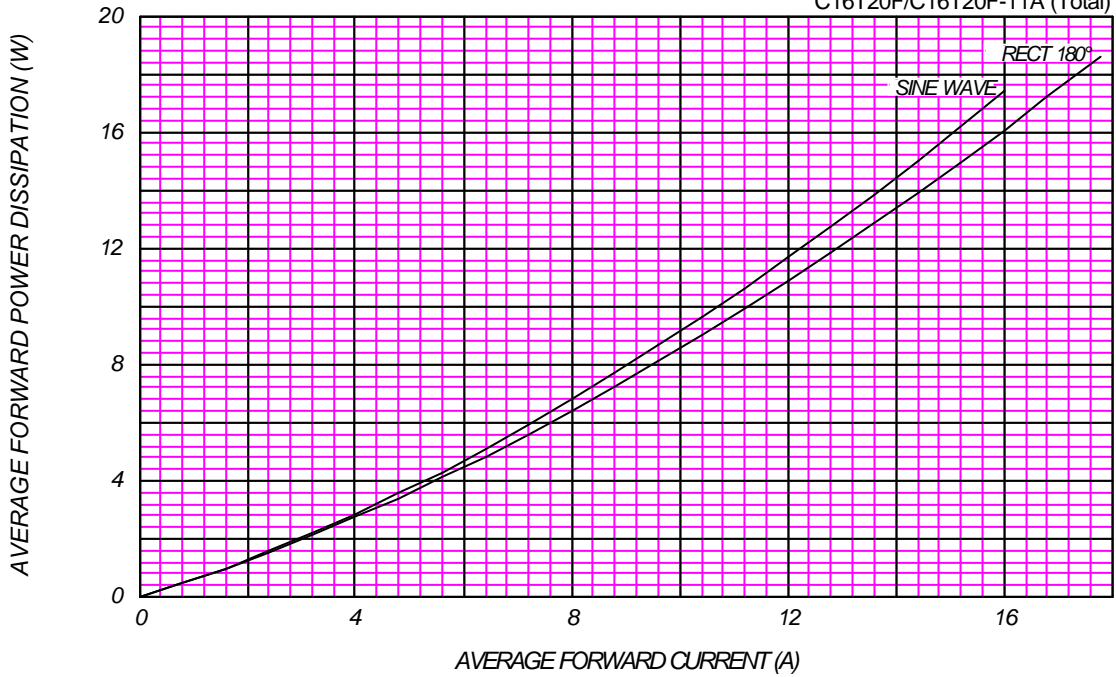
10ms Sine Wave Single Pulse

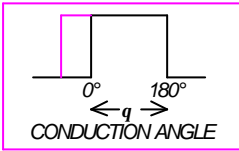
C16T20F/C16T20F-11A (per Arm)



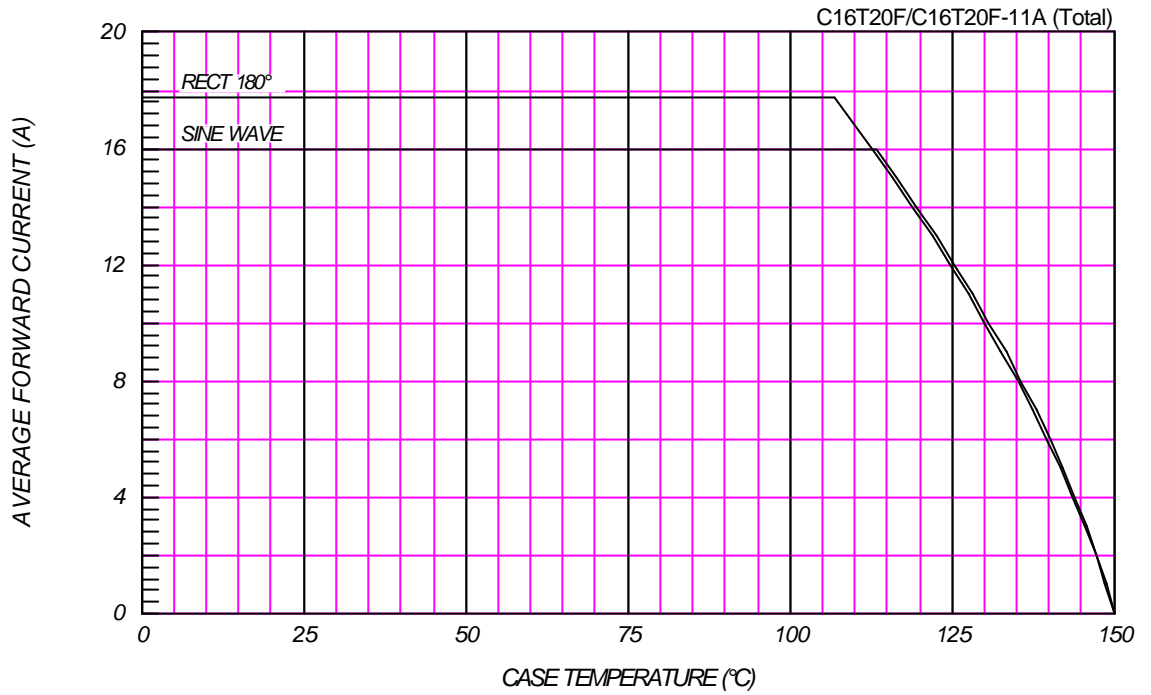
AVERAGE FORWARD POWER DISSIPATION

C16T20F/C16T20F-11A (Total)





### AVERAGE FORWARD CURRENT VS. CASE TEMPERATURE



### SURGE CURRENT RATINGS

f=50Hz, Sine Wave, Non-Repetitive, No Load

